

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address COMMISSIONER OF PATENTS AND TRADEMARKS PO Box 1450 Alexandra, Virguna 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/974,582	10/09/2001	Ming-Chung Liang	JCLA7521	8293
7	590 05/21/2003			
J.C. Patents, Inc.			EXAMINER	
Suite 250 4 Venture			MACKEY, TERRENCE M	
Irvine, CA 92	618		ART UNIT	PAPER NUMBER
			1765	٠٦
			DATE MAILED: 05/21/2003	_)

Please find below and/or attached an Office communication concerning this application or proceeding.

•		AS-3
	Application No.	Applicant(s)
Office Action Summan	09/974,582	LIANG, MING-CHUNG
Office Action Summary	Examiner	Art Unit
	Terrence Mackey	1765
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet wi	th the correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a rep If NO period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b). Status		eply be timely filed (30) days will be considered timely. THS from the mailing date of this communication. ANDONED (35 U.S.C. § 133).
1) Responsive to communication(s) filed on	·	
2a) This action is FINAL . 2b) ∑ T	his action is non-final.	
3) Since this application is in condition for allow closed in accordance with the practice under Disposition of Claims		
4) \bigcirc Claim(s) <u>1 - 22</u> is/are pending in the application	ion.	
4a) Of the above claim(s) is/are withdra	awn from consideration.	
5) Claim(s) is/are allowed.		
6) Claım(s) <u>1 - 22</u> is/are rejected.		
7) Claim(s) is/are objected to.		
8) Claim(s) are subject to restriction and/	or election requirement.	
Application Papers		
9) ☑ The specification is objected to by the Examin	er.	
10) The drawing(s) filed on is/are: a) acce	epted or b) objected to by t	ne Examiner.
Applicant may not request that any objection to t	he drawing(s) be held in abeya	ince. See 37 CFR 1.85(a).
11) The proposed drawing correction filed on	_ is: a)□ approved b)□ d	isapproved by the Examiner.
If approved, corrected drawings are required in re	• •	
12) ☐ The oath or declaration is objected to by the E	xaminer.	
Priority under 35 U.S.C. §§ 119 and 120		
13)⊡ Acknowledgment is made of a claim for foreig	gn priority under 35 U.S.C. {	§ 119(a)-(d) or (f).
a)⊠ All b) Some * c) None of:		
1. Certified copies of the priority documer	nts have been received.	
2. Certified copies of the priority documer	nts have been received in A	pplication No
 3. Copies of the certified copies of the pricapplication from the International B * See the attached detailed Office action for a lis 	ureau (PCT Rule 17.2(a)).	-
14) Acknowledgment is made of a claim for domes	tic priority under 35 U.S.C.	§ 119(e) (to a provisional application).
 a) The translation of the foreign language present 15) Acknowledgment is made of a claim for domes 	• •	
Attachment(s)		
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s) 	5) Notice of I	Summary (PTO-413) Paper No(s) nformal Patent Application (PTO-152)

Application/Control Number: 09/974,582

Art Unit: 1765

DETAILED ACTION

Specification

The disclosure is objected to because of the following informalities: etching rates on pages 6 and 7 are lacking units of measure and the etching uniformity parameter disclosed on page 7 is inadequately described.

Appropriate correction is required.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claim 9 recites the limitation "partially fluoro-substituted alkane gas" in line 1.

There is insufficient antecedent basis for this limitation in the claim.

Claim 15 recites the limitation "a ratio of CHF₃ to CF₄" in line 1. There is insufficient antecedent basis for this limitation in the claim.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Application/Control Number: 09/974,582

Art Unit: 1765

Claims 1 – 22 are rejected under 35 U.S.C. 102(a) as being anticipated by Arleo et al. (5,176,790). Applicant claims a plasma etching gas and process for etching a silicon oxide layer using the etching gas. The etching gas consists of a fluoroalkane gas and nitrogen gas. The nitrogen gas has a flow rate of about 1 sccm to about 50 sccm. The fluoroalkane gas may comprise a mixture of a partially fluoro-substituted alkane gas (CH₃F, CHF₃, and CH₂F₂) and a fully fluoro-substituted alkane gas (CF₄, C_2F_6 , C_3F_8 , and C_4F_8) in a ratio of about 3/1 to 15/1. The etching gas may further comprise argon gas having a flow rate of about 50 sccm to about 150 sccm.

Arleo et al. disclose a process for plasma etching vias in a silicon oxide layer on an integrated circuit substrate by flowing an etchant gas composition comprising about 3 sccm of N₂, about 25 sccm of CHF₃, about 5 sccm of CF₄, and about 75 sccm of argon (column 7, lines 4-8).

Conclusion

Remaining references cited of interest to show the state of the art.

No claim is allowed.

Papers relating to this application may be submitted to Technology Sector 1700 by facsimile transmission. Papers should be faxed to Crystal Plaza 3, Art Unit 1765, using fax number (703) 305-6357. All Technology Section 1700 fax machines are available to receive transmissions 24 hrs/day, 7 days/wk. Please note that the faxing of such papers must conform to the Notice published in the Official Gazette, 1096 OG 30, (November 15, 1989).

Application/Control Number: 09/974,582

Art Unit: 1765

Any inquiry concerning this communication or earlier communications from the Examiner should be directed to Terrence Mackey whose telephone number is (703) 305-5504. The Examiner can normally be reached Monday - Friday from 7:00 AM – 4:30 PM.

If attempts to reach the Examiner by telephone are unsuccessful, the examiner's supervisor, Ben Uteck, can be reached at (703) 308-3836.

Any inquiry of a general nature or relating to the status of this application should be directed to the receptionist whose telephone number is (703) 308-0661.

MMT

May 13, 2003

PRIMARY EXAMINEP